



A Product Line of Diodes Incorporated



### **60V N-CHANNEL ENHANCEMENT MODE VERTICAL DMOS FET IN E-LINE**

### **Product Summary**

V <sub>(BR)DSS</sub>	Max R <sub>DS(on)</sub>	<b>Max I<sub>D</sub></b> @ T <sub>A</sub> = 25°C
60V	$330 \mathrm{m}\Omega @ \mathrm{V}_{\mathrm{GS}} = 10 \mathrm{V}$	1.4A
	$450 \mathrm{m}\Omega @ \mathrm{V}_{\mathrm{GS}} = 5\mathrm{V}$	1.2A

# Application

- DC DC convertors
- Solenoids / relay drivers for automotive

## **Features and Benefits**

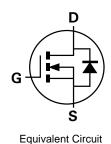
- Breakdown Voltage BV<sub>DSS</sub> > 60V
- R<sub>DS(on)</sub> ≤ 0.33Ω @ V<sub>GS</sub> = 10V
- Maximum continuous drain current I<sub>D</sub> = 1.1A
- "Green" component, Lead Free Finish / RoHS compliant (Note 1)
- Qualified to AEC-Q101 Standards for High Reliability

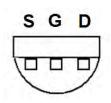
## **Mechanical Data**

- Case: E-Line (TO-92 Compatible)
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish
- Weight: 0.159 grams (approximate)



E-Line





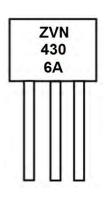
Pin Out - Bottom View

## Ordering Information (Note 1)

Part Number	Package	Marking	Quantity
ZVN4306ASTZ	E-Line	ZVN4306A	2,000 per Ammo pack
ZVN4306A	E-Line	ZVN4306A	4,000 loose per box

Notes: 1. Diodes, Inc. defines "Green" products as those which are RoHS compliant and contain no halogens or antimony compounds. All applicable RoHS exemptions applied. Further information about Diodes Inc.'s "Green" Policy can be found on our website at http:// www.diodes.com

# **Marking Information**



ZVN4306A = Product Type Marking Code On Rounded Face





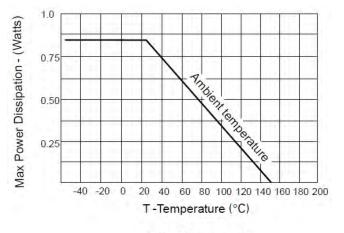
### Maximum Ratings @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Drain-Source Voltage	V <sub>DSS</sub>	60	V
Gate-Source Voltage	V <sub>GSS</sub>	±20	V
Continuous Drain Current	Ι <sub>D</sub>	1.1	А
Practical Continuous Drain Current	I <sub>DP</sub>	1.3	А
Pulsed Drain Current	I <sub>DM</sub>	15	А

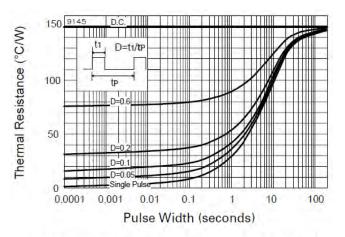
# Thermal Characteristics @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic		Symbol	Value	Unit
Power Dissipation		PD	850	mW
Practical Power Dissipation	(Note 2)	P <sub>DP</sub>	1.13	W
Thermal Resistance, Junction to Ambient		R <sub>θJA</sub>	150	°C/W
Thermal Resistance, Junction to Ambient	(Note 2)	R <sub>0JA</sub>	111	°C/W
Thermal Resistance, Junction to Leads	(Note 3)	R <sub>θJL</sub>	50	°C/W
Operating and Storage Temperature Range		T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

Notes: 2. For a device mounted on 25mm X 25mm X 1.6mm FR-4 PCB with high coverage of single sided 1oz copper, in still air condition. 3. Thermal resistance from junction to solder-point



**Derating curve** 



## Maximum transient thermal impedance





# Electrical Characteristics @T<sub>A</sub> = 25°C unless otherwise specified

			-			
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 4)						
Drain-Source Breakdown Voltage	<b>BV</b> <sub>DSS</sub>	60	-	-	V	$V_{GS} = 0V, I_D = 1mA$
Zero Gate Voltage Drain Current T <sub>J</sub> = 25°C	I <sub>DSS</sub>	-	-	1 20	μA	V <sub>DS</sub> = 60V, V <sub>GS</sub> = 0V V <sub>DS</sub> = 48V, V <sub>GS</sub> = 0V, T <sub>A</sub> = 125°C
Gate-Source Leakage	I <sub>GSS</sub>	-	-	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$
On-State Drain Current	I <sub>D(on)</sub>	12	-	-	А	$V_{GS} = 10V, V_{DS} = 10V$
ON CHARACTERISTICS (Note 4)						
Gate Threshold Voltage	V <sub>GS(th)</sub>	1.3	-	3	V	$V_{DS} = V_{GS}$ , $I_D = 1mA$
Static Drain-Source On-Resistance	R <sub>DS (on)</sub>	-	0.22 0.32	0.33 0.45	Ω	$V_{GS} = 10V, I_D = 3A$ $V_{GS} = 5V, I_D = 1.5A$
Forward Transconductance	<b>g</b> fs	700	-	-	mS	$V_{DS} = 10V, I_{D} = 3A$
DYNAMIC CHARACTERISTICS (Note 4)	• -					•
Input Capacitance	Ciss	-	-	350	pF	
Output Capacitance	Coss	-	-	140	pF	$V_{DS} = 25V, V_{GS} = 0V,$ f = 1.0MHz
Reverse Transfer Capacitance	Crss	-	-	30	pF	
Turn-On Delay Time (Note 5)	t <sub>d(on)</sub>	-	-	8	ns	
Turn-On Rise Time (Note 5)	tr	-	-	25	ns	
Turn-Off Delay Time (Note 5)	t <sub>d(off)</sub>	-	-	30	ns	$V_{DD} = 25V, I_D = 3A, V_{GEM} = 10V$
Turn-Off Fall Time (Note 5)	t <sub>f</sub>	-	-	16	ns	

Notes:

4. Measured under pulsed conditions. Width = 300 $\mu$ s. Duty cycle < 2% 5. Switching times measured with 50 $\Omega$  source impedance and <5ns rise time on a pulse generator





#### **Electrical Characteristics** VGS= 20V 12V 10V 9V 8V VGS=3V 3.5V 5V 6V (C) 12 10 RDS(on)-Drain Source On Resistance 11 7V 10 ID - Drain Current (Amps) 9 8 6V 7 6 5 4 3 2 1.0 5V 10V 4V 1 3.5V 3V 0 0.1 5 6 0 1 2 3 4 7 8 9 10 100 0.1 1 10 ID-Drain Current (Amps) VDs - Drain Source Voltage (Volts) On-resistance v drain current **Saturation Characteristics** 2.6 5 Normalised RDS(on) and VGS(th) 2.4 VGS=10V gfs-Transconductance (S) ID=3A 4 2.2 2.0 POS Source Resistance 3 1.8 1.6 VDS=10V 2 1.4 Drain 1.2 VGS=VDS 1 ID=1mA 1.0 0.8 0 Gate Threshold Voltage VGS(TH) 0.6 0 2 4 6 8 10 12 14 16 18 20 -50 -25 0 25 50 75 100 125 150 175 200 225 ID(on)- Drain Current (Amps) Tj-Junction Temperature (°C) Transconductance v drain current Normalised RDs(on) and VGs(th) v Temperature VDD= 16 20V 40V 500 VGS-Gate Source Voltage (Volts) 14 D-3A 60V 400 12 C-Capacitance (pF) 10 300 8 Ciss 6 200 4 100 Coss 2 Crss 0 0 0 1 2 3 4 5 6 7 8 9 10 11 12 20 30 40 60 70 0 10 50 80 Q-Charge (nC) VDS-Drain Source Voltage (Volts) Gate charge v gate-source voltage Capacitance v drain-source voltage

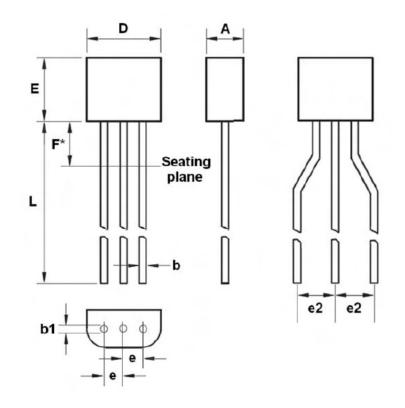
ZVN4306A

Document number: DS33367 Rev. 4 - 2





# **Package Outline Dimensions**



A	Millin	neters	Inches		
	Min.	Max.	Min.	Max.	
	2.16 2.41		0.085	0.095	
b	0.41	0.495	0.016	0.0195	
b1	0.41	0.495	0.016	0.0195	
D	4.37	4.77	0.172	0.188	
E	3.61	3.61 4.01		0.158	
e*	1.27	1.27 NOM		NOM	
e <sup>†</sup>	2.54 NOM		0.100	NOM	
F <sup>‡</sup>		2.50	-	0.098	
L	13.00	13.97	0.512	0.550	

### NOTES:

\* loose product only

† taped product only

‡ leads uncontrolled above seating plane

Controlling dimensions are in millimeters. Approximate dimensions are provided in inches





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